Thin Films E5125 Learning goals

Student can describe the following concepts and compare them with each other.

Surface engineering and vacuum

- Surface phenomena
 - Adsorption&desorption
 - o Surface diffusion
- Energetic ion-surface interactions
- Vacuum
 - Vacuum system
 - o Pressure units
 - Residual gas
 - o Formation time of a monolayer on surface
 - o Pumps
 - Vacuum gauges

PVD

- Principle ideas of plasma: glow discharge and arc
- Sputter mechanism
- Thorton diagram: microstructure as function of ion energy and substrate temperature
- Subplantation
- Residual stress
- Magnetron sputtering
- Pulsed MS (HIPIMS)
- Reactive sputtering
- Arc deposion
- Pulsed laser deposition
- Applications

Characterization

- Role of vacuum in characterization methods
- Thickness
- Residual stress
- ion beam characterization
 - o SIMS
 - Rutherford Back Scattering (RBS), and Forward Recoil Spectroscopy
- X-ray spectroscopy
 - o Glancing angle XRD
 - o X-ray reflection XRR
- XPS- ESCA
- RAMAN
- Indentation, nanoindentation

CVD/ALD

- Thermal CVD process,
 - o Precursors
 - Mass transport
 - o Silicon growth
- Plasma assisted CVD
 - Plasma enabling lower deposition temperature
 - Hydrogen content
 - Reactor architectures
- ALD
 - Growth process
 - o Process window
 - o Reactor architectures
 - Conformality
 - Materials
- Applications

Learning by teaching by "Walkin Gallery"

- Reading scientific articles and select main content to a poster
- Present a poster
- Discuss and ask relevant questions on a poster presentation

Learning to produce a video presentation